



NCS199A1R, NCS199A2R, NCS199A3R

Table 1. MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Supply Voltage (Note 1)		V_S	+30	V
Analog Inputs	Differential (V_{IN+})–(V_{IN-})	V_{IN+}, V_{IN-}	–30 to +30	V
	Common–Mode (Note 2)		(GND–0.3) to +30	
REF Input		V_{REF}	(GND–0.3) to (V_S +0.3)	V
Output (Note 2)		V_{OUT}	(GND–0.3) to (V_S +0.3)	V
Input Current into Any Pin (Note 2)			5	mA
Maximum Junction Temperature		$T_{J(max)}$	+150	°C
Storage Temperature Range		T_{STG}	–65 to +150	°C
ESD Capability, Human Body Model (Note 3)		HBM	±2000	V
Charged Device Model (Note 3)		CDM	±2000	V
Latch–Up Current (Note 4)		I_{LU}	100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NCS199A1R, NCS199A2R, NCS199A3R

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$ AND $V_{REF} = V_S/2$ UNLESS OTHERWISE NOTED.)
(THE NCS199A3R IS USED FOR TYPICAL CHARACTERISTICS)

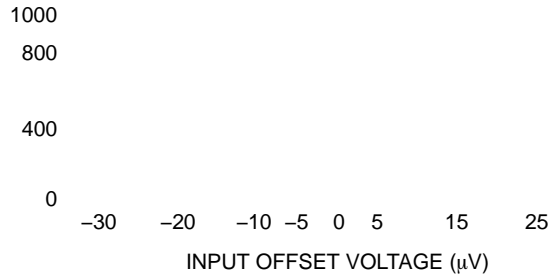


Figure 1. Input Offset Voltage Production Distribution

TEMPERATURE ($^\circ\text{C}$)

Figure 2. Input Offset Voltage vs. Temperature

NCS199A1R, NCS199A2R, NCS199A3R

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, $V_S = 5\text{ V}$, $V_{IN+} = 12\text{ V}$ AND $V_{REF} = V_S/2$ UNLESS OTHERWISE NOTED.)
(THE NCS199A3R IS USED FOR TYPICAL CHARACTERISTICS)

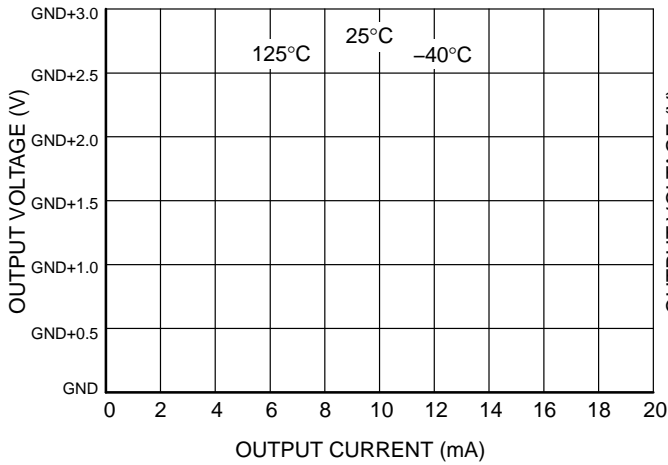


Figure 13. Negative Output Voltage Swing vs. Output Current, $V_S = 2.7\text{ V}$

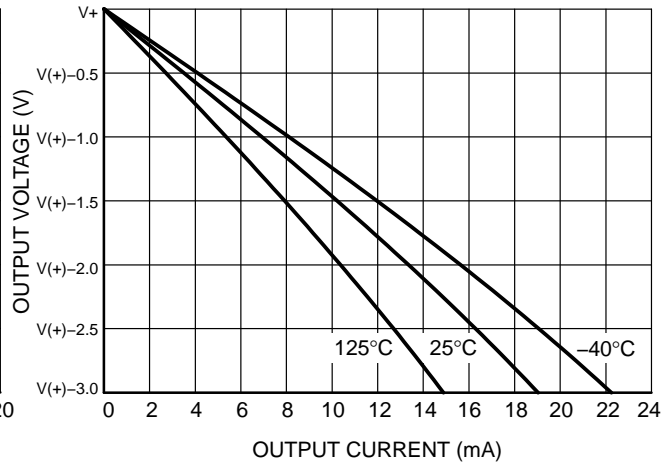


Figure 14. Positive Output Voltage Swing vs. Output Current, $V_S = 5\text{ V}$

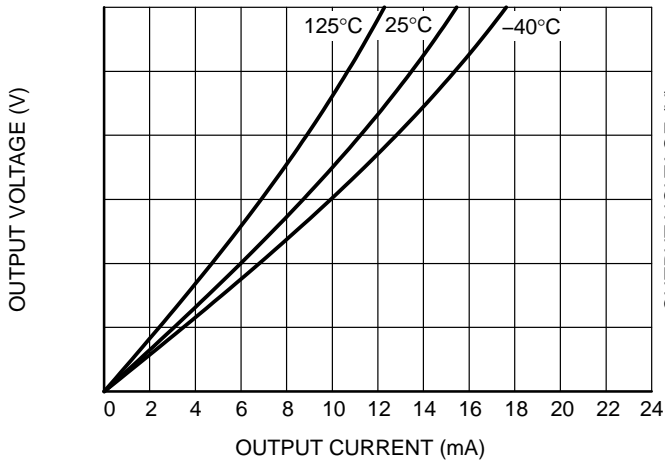


Figure 15. Negative Output Voltage Swing vs. Output Current, $V_S = 5\text{ V}$

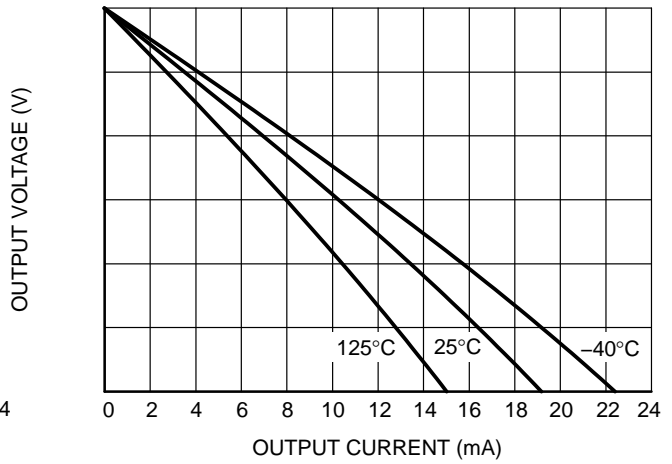


Figure 16. Positive Output Voltage Swing vs. Output Current, $V_S = 26\text{ V}$

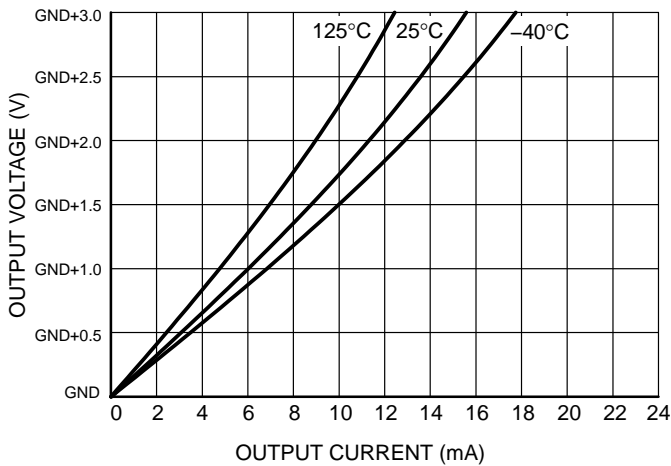


Figure 17. Negative Output Voltage Swing vs. Output Current, $V_S = 26\text{ V}$

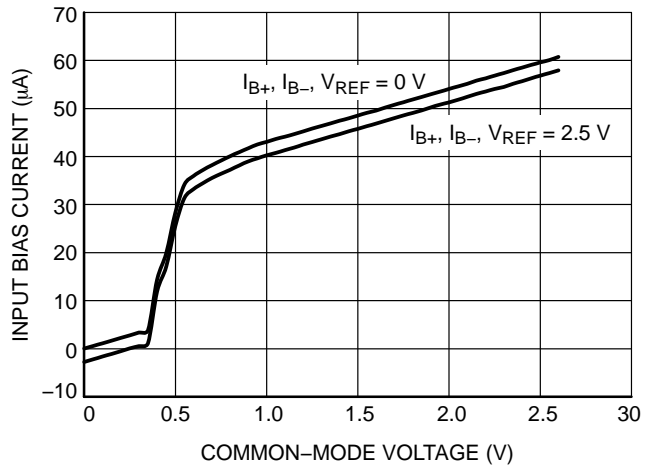


Figure 18. Input Bias Current vs. Common Mode Voltage with $V_S = 5\text{ V}$

TYPICAL CHARACTERISTICS

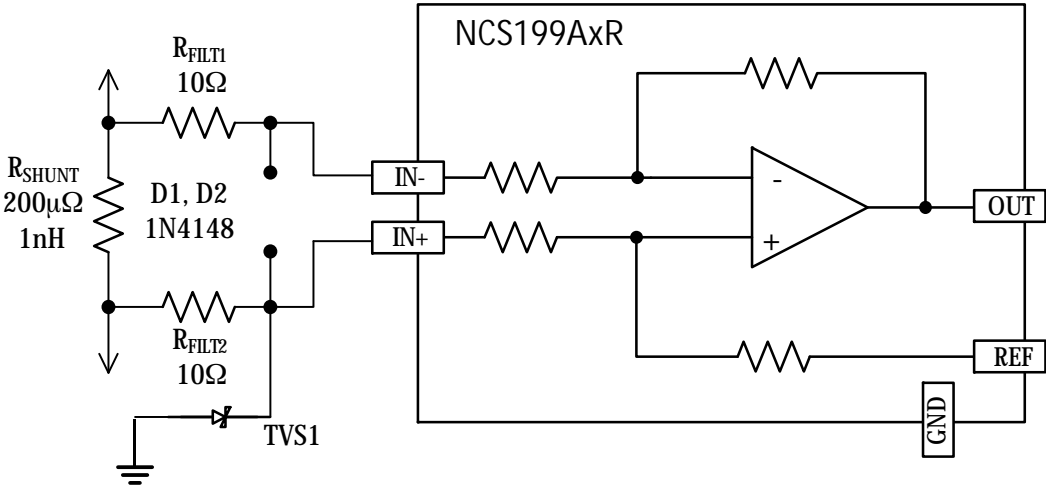
BASIC CONNECTIONS

Current Sensing Techniques

The NCS199AxR current-sense amplifiers can be configured for both low-side and high-side current sensing. Low-side sensing appears to have the advantage of being straightforward,

NCS199A1R, NCS199A2R, NCS199A3R

NCS199A1R, NCS199A2R, NCS199A3R



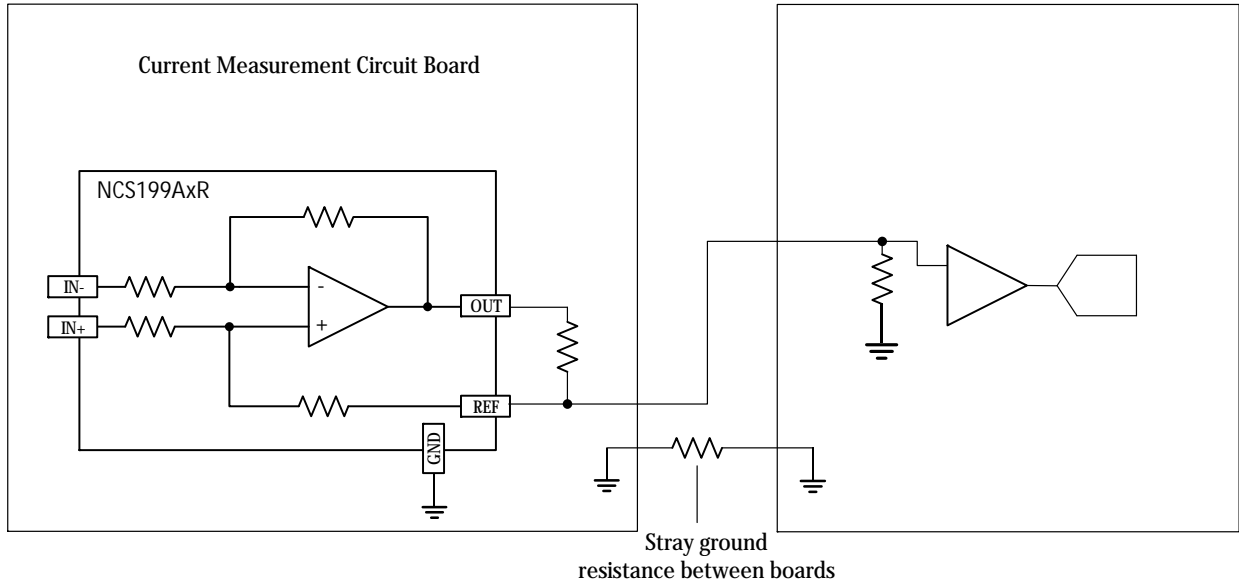
NCS199A1R, NCS199A2R, NCS199A3R



Figure 35. Surface Mount Kelvin Shunt

Current Output Configuration

In applications where the readout boards are remotely located, the voltage output of the NCS199AxR can be converted to a precision current output. The precision output current measurements are read more accurately as it overcomes the errors due to ground drops between the boards.



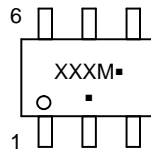


SC-88 2.00x1.25x0.90, 0.65P
CASE 419B-02
ISSUE Z

DATE 18 APR 2024

BURRS, MOLD FLASH,
PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25

**GENERIC
MARKING DIAGRAM***



XXX = Specific Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED MOUNTING

STYLES ON PAGE 2

STYLE 1:
PIN 1. EMITTER 2
2. BASE 2
3. COLLECTOR 1
4. EMITTER 1
5. BASE 1
6. COLLECTOR 2

STYLE 2:
CANCELLED

STYLE 3:
CANCELLED

onsemi, **onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi**
